Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a 6 bumps Wafer Level Chip-Size Package (WLCSP) using Trench MOSFET technology.

2. Features and benefits

- · Low threshold voltage
- Ultra small package: 0.98 × 1.48 × 0.35 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- · Relay driver
- · High-speed line driver
- · Low-side loadswitch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V_{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	$V_{GS} = 4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$	[1]	-	-	8.7	Α
Static characte	Static characteristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 3 \text{ A}; T_j = 25 \text{ °C}$		-	17	21	mΩ

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm²



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
A1	G	gate	1 2	D
A2	S	source	A	
B1	S	source	В	G ←
B2	S	source		
C1	D	drain	c O	
C2	D	drain	Transparent top view WLCSP6 (WLCSP6_3-2)	S 017aaa255

6. Ordering information

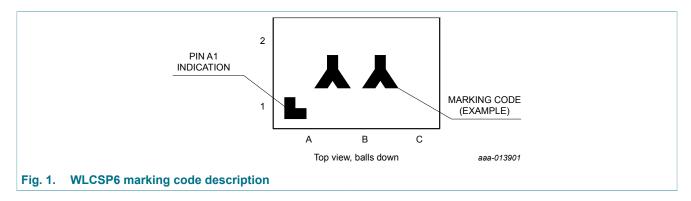
Table 3. Ordering information

Type number	Package	age				
	Name	Description	Version			
PMCM6501UNE	WLCSP6	wafer level chip-size package; 6 bumps (3 x 2)	WLCSP6_3-2			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMCM6501UNE	AE



8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	8.7	Α
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	6.6	Α
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	4.2	Α
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	27	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	556	mW
			[1]	-	1.3	W
		T _{sp} = 25 °C		-	12.5	W
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source Drai	n Diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	1.2	Α

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm²
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

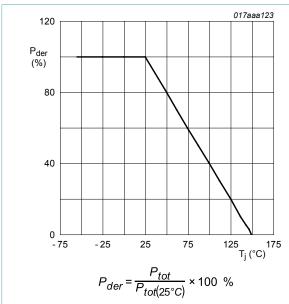


Fig. 2. Normalized total power dissipation as a function of junction temperature

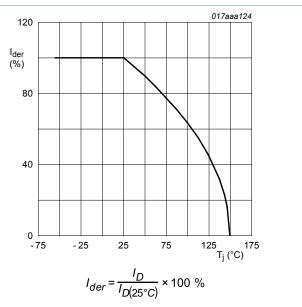
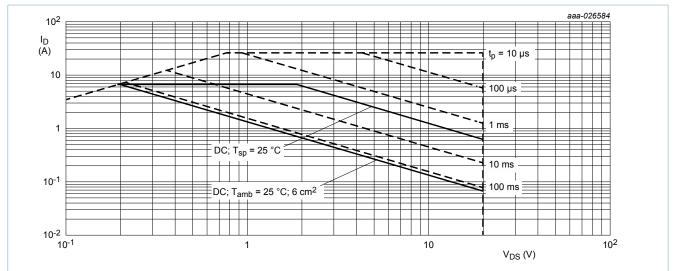


Fig. 3. Normalized continuous drain current as a function of junction temperature

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20 V, N-channel Trench MOSFET



Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j a)	thermal resistance from junction to ambient	in free air	[1]	-	180	225	K/W
			<u>[2]</u>	-	65	85	K/W
			<u>[3]</u>	-	75	95	K/W
		t ≤ 5 s	<u>[3]</u>	-	45	55	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

- Device mounted on an FR4 Printed-Circuit Board (PCB), single sided-copper; tin-plated and standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain, 4 layer, 1 cm²
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

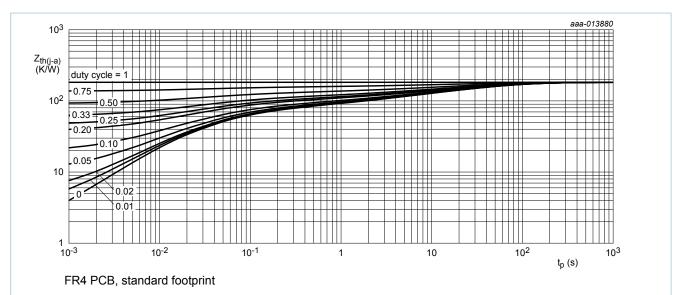


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

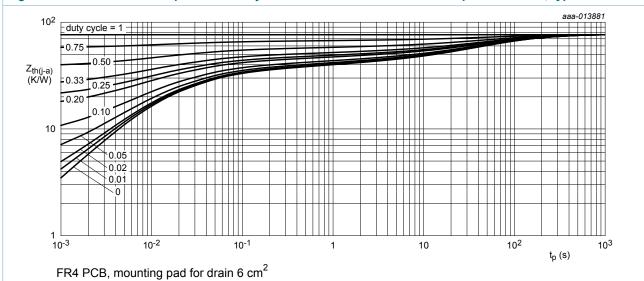


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		,			
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	20	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	0.4	0.6	0.9	V
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	$V_{GS} = 8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		$V_{GS} = 4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μA
		$V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-1	μA
		$V_{GS} = 2.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	200	nA
		$V_{GS} = -2.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-200	nA
R _{DSon} drain-source on-state resistance	drain-source on-state	$V_{GS} = 4.5 \text{ V}; I_D = 3 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	17	21	mΩ
	resistance	$V_{GS} = 4.5 \text{ V}; I_D = 3 \text{ A}; T_j = 150 ^{\circ}\text{C}$	-	25	29	mΩ
		$V_{GS} = 2.5 \text{ V}; I_D = 3 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	20	25	mΩ
		$V_{GS} = 1.8 \text{ V}; I_D = 2 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	22	32	mΩ
		$V_{GS} = 1.5 \text{ V}; I_D = 1 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	30	45	mΩ
9fs	forward transconductance	$V_{DS} = 5 \text{ V}; I_D = 3 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	40	-	S
R_G	gate resistance	f = 1 MHz; T _j = 25 °C	-	1.2	-	Ω
Dynamic ch	naracteristics					
Q _{G(tot)}	total gate charge	$V_{DS} = 10 \text{ V}; I_D = 3 \text{ A}; V_{GS} = 4.5 \text{ V};$	-	19	28	nC
Q_{GS}	gate-source charge	T _j = 25 °C	-	1.2	-	nC
Q_{GD}	gate-drain charge		-	5.8	-	nC
C _{iss}	input capacitance	$V_{DS} = 10 \text{ V}; f = 1 \text{ MHz}; V_{GS} = 0 \text{ V};$	-	105	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	19	-	pF
C _{rss}	reverse transfer capacitance		-	18	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; I_{D} = 6.6 A; V_{GS} = 4.5 V;	-	7.3	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	28	-	ns
t _{d(off)}	turn-off delay time		-	100	-	ns
t _f	fall time		-	46	-	ns
Source-dra	in diode					
V_{SD}	source-drain voltage	I _S = 1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	0.6	1.2	V

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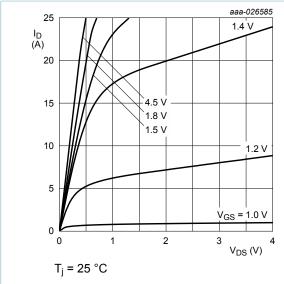


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

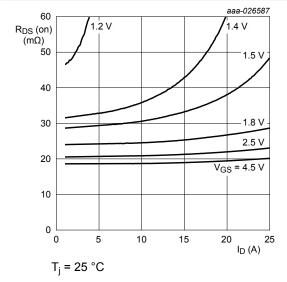


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

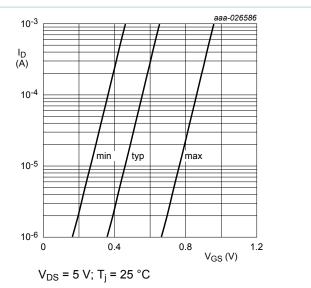


Fig. 8. Sub-threshold drain current as a function of gate-source voltage

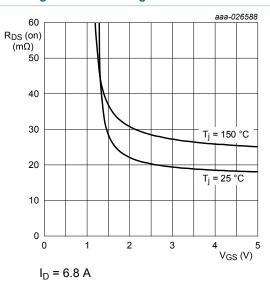


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

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20 V, N-channel Trench MOSFET

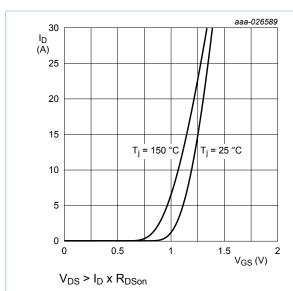


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

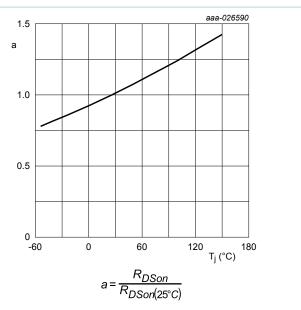


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

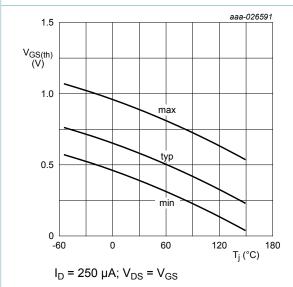


Fig. 13. Gate-source threshold voltage as a function of junction temperature

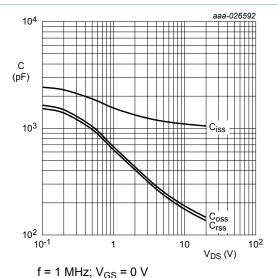
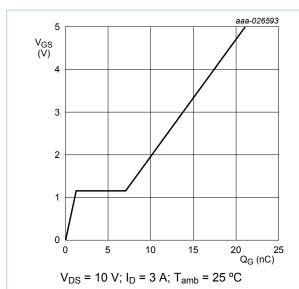


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

8 / 15



V_{GS}(th)
V_{GS}
Q_{GS1}
Q_{GS2}
Q_{GG(tot)}
003aaa508

Fig. 15. Gate-source voltage as a function of gate charge; typical values

Fig. 16. Gate charge waveform definitions

 $V_{GS(pl)} \\$

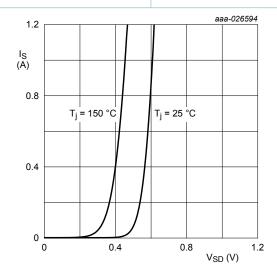
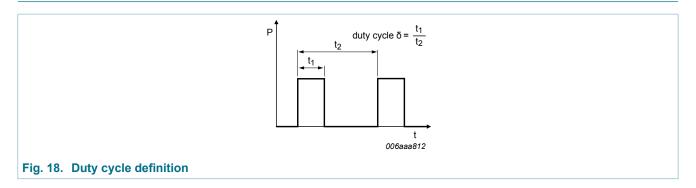


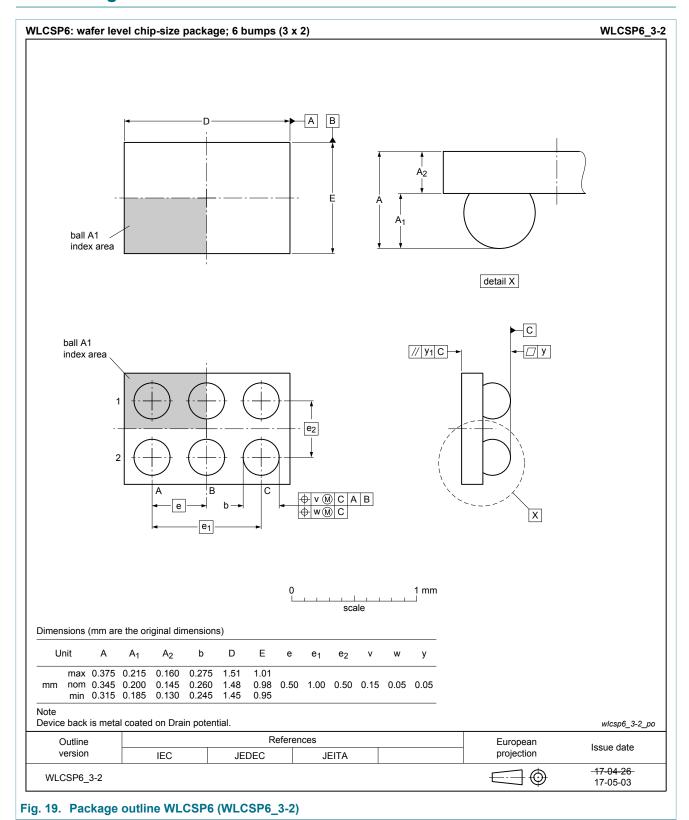
Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information

 $V_{GS} = 0 V$

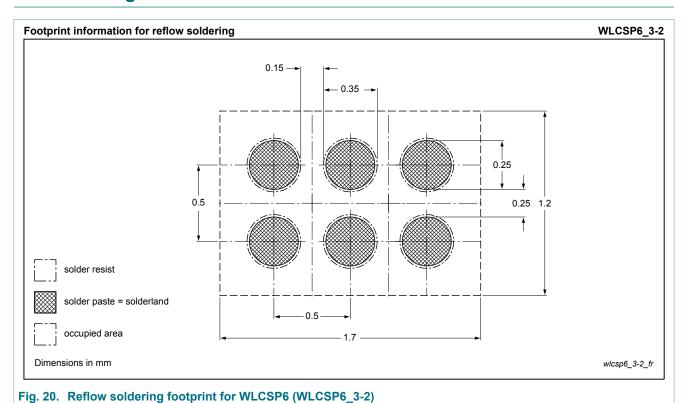


12. Package outline



10 / 15

13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMCM6501UNE v.1	20170530	Product data sheet	-	-

12 / 15

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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16. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	Characteristics	б
11.	Test information	9
12.	Package outline	10
13.	Soldering	11
14.	Revision history	12
15.	Legal information	. 13

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